

HD74LV07A

Hex Buffers / Drivers with Open Drain Outputs

REJ03D0231-0600 Rev.6.00 Dec 22, 2005

Description

The HD74LV07A has six buffers / drivers with open drain outputs in a 14-pin package.

Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- All outputs V_0 (Max.) = 5.5 V (@ V_{CC} = 0 V)
- All outputs V_0 (Max.) = 5.5 V (@ V_{CC} = 2.0 V to 5.5 V, Output "Z" state)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Output current: ± 8 mA (@V_{CC} = 3.0 V to 3.6 V), ± 16 mA (@V_{CC} = 4.5 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV07AFPEL	SOP-14 pin(JEITA)	PRSP0014DF-B (FP-14DAV)	FP	EL (2,000 pcs/reel)
HD74LV07ARPEL	SOP-14 pin(JEDEC)	PRSP0014DE-A (FP-14DNV)	RP	EL (2,500 pcs/reel)
HD74LV07ATELL	TSSOP-14 pin	PTSP0014JA-B (TTP–14DV)	Т	ELL (2,000 pcs/reel)

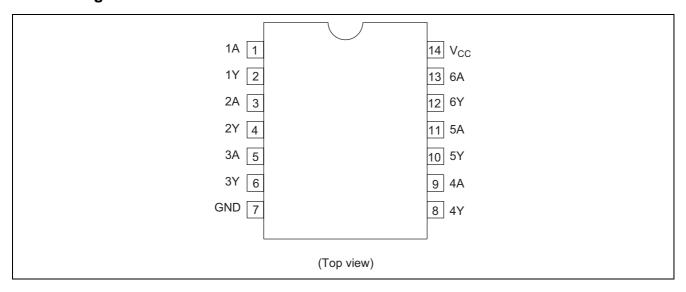
Note: Please consult the sales office for the above package availability.

Function Table

Input A	Output Y
L	L
Н	Z

Note: H: High level
L: Low level
Z: High impedance

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	Vcc	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	-0.5 to V _{CC} + 0.5	V	Output: L
		-0.5 to 7.0		V _{CC} : OFF or Output: Z
Input clamp current	I _{IK}	-20	mA	V _I < 0
Output clamp current	I _{OK}	±50	mA	V _O < 0
Continuous output current	I ₀	±35	mA	$V_O = 0$ to V_{CC}
Continuous current through	I _{CC} or	±50	mA	
V _{CC} or GND	I_{GND}			
Maximum power dissipation at	PT	785	mW	SOP
Ta = 25°C (in still air)*3		500		TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 7.0 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	2.0	5.5	V	
Input voltage range	Vı	0	5.5	V	
Output voltage range	Vo	0	5.5	V	
Output current	I _{OL}	_	50	μΑ	V _{CC} = 2.0 V
		_	2	mA	V _{CC} = 2.3 to 2.7 V
		_	8		V _{CC} = 3.0 to 3.6 V
		_	16		V _{CC} = 4.5 to 5.5 V
Input transition rise or fall rate	Δt / Δv	0	200	ns/V	V _{CC} = 2.3 to 2.7 V
		0	100		V _{CC} = 3.0 to 3.6 V
		0	20	1	V _{CC} = 4.5 to 5.5 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Logic Diagram



DC Electrical Characteristics

 $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{CC} \times 0.7$	_	_		
		3.0 to 3.6	$V_{CC} \times 0.7$	_	_		
		4.5 to 5.5	$V_{CC} \times 0.7$	_	_		
	V_{IL}	2.0	_	_	0.5		
		2.3 to 2.7	_	_	$V_{CC} \times 0.3$		
		3.0 to 3.6	_	_	$V_{CC} \times 0.3$		
		4.5 to 5.5	_	_	$V_{CC} \times 0.3$		
Output voltage	V_{OL}	Min to Max	_	_	0.1	V	$I_{OL} = 50 \mu\text{A}$
		2.3	_	_	0.4		$I_{OL} = 2 \text{ mA}$
		3.0	_	_	0.44		$I_{OL} = 8 \text{ mA}$
		4.5	_	_	0.55		$I_{OL} = 16 \text{ mA}$
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Off state output	l _{OZ}	Min to Max	_	_	2.5	μΑ	$V_0 = 5.5 \text{ V}$
current							
Quiescent supply	I _{CC}	5.5	_	_	20	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
current							
Output leakage	I _{OFF}	0	_	_	5	μΑ	V_{I} or $V_{O} = 0$ to 5.5 V
current							
Input capacitance	C _{IN}	3.3	_	2.3	_	pF	$V_I = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

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Switching Characteristics

 $V_{CC}=2.5\pm0.2\ V$

Item	Symbol	T	a = 25°	С	Ta = -40	to 85°C	Unit	Test	FROM	ТО
item	Syllibol	Min	Тур	Max	Min	Max	Ullit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	4.7	10.4	1.0	13.0	ns	$C_L = 15 pF$	Α	Υ
delay time		_	9.5	15.2	1.0	18.0		C _L = 50 pF		
	t _{PHL}	_	5.4	10.4	1.0	13.0		C _L = 15 pF		
		_	7.9	15.2	1.0	18.0		$C_L = 50 pF$		

 $V_{CC}=3.3\pm0.3~V$

Item	Symbol	T	a = 25°	С	Ta = -40	to 85°C	Unit	Test	FROM	ТО
item	Symbol	Min	Тур	Max	Min	Max	Ollit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	4.0	7.1	1.0	8.5	ns	C _L = 15 pF	Α	Υ
delay time		_	7.3	10.6	1.0	12.0		C _L = 50 pF		
	t _{PHL}	_	4.3	7.1	1.0	8.5		C _L = 15 pF		
		_	5.8	10.6	1.0	12.0		C _L = 50 pF		

 $V_{CC}=5.0\pm0.5~V$

Item	Symbol	Ta = 25°C		Ta = -40 to 85°C		Unit	Test	FROM	ТО	
item	Symbol	Min	Тур	Max	Min	Max	Ollit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	3.3	5.5	1.0	6.5	ns	$C_L = 15 pF$	Α	Υ
delay time		_	5.6	7.5	1.0	8.5		C _L = 50 pF		
	t _{PHL}	_	3.4	5.5	1.0	6.5		C _L = 15 pF		
		_	4.1	7.5	1.0	8.5		C _L = 50 pF		

Operating Characteristics

 $C_L = 50 \text{ pF}$

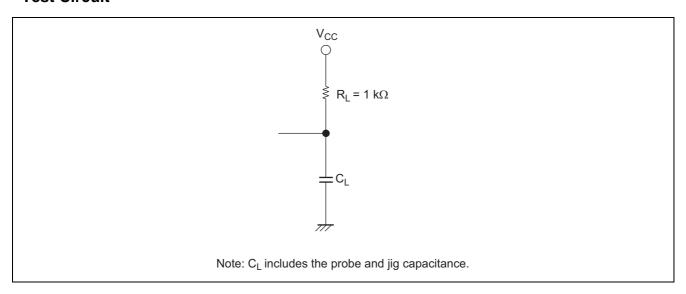
Itom	Item Symbol V _{CC}		Ta = 25°C		Ta = 25°C		Test Conditions	
item	Syllibol	V _{CC} (V)	Min	Тур	Max	Unit	rest conditions	
Power dissipation capacitance	C_{PD}	3.3	_	9.6	_	pF	f = 10 MHz	
		5.0	_	11.4	_			

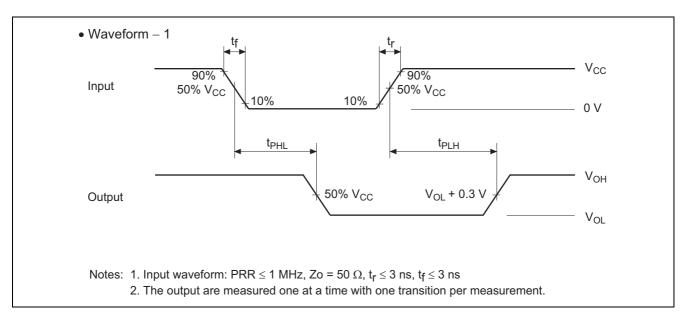
Noise Characteristics

 $C_L = 50 \text{ pF}$

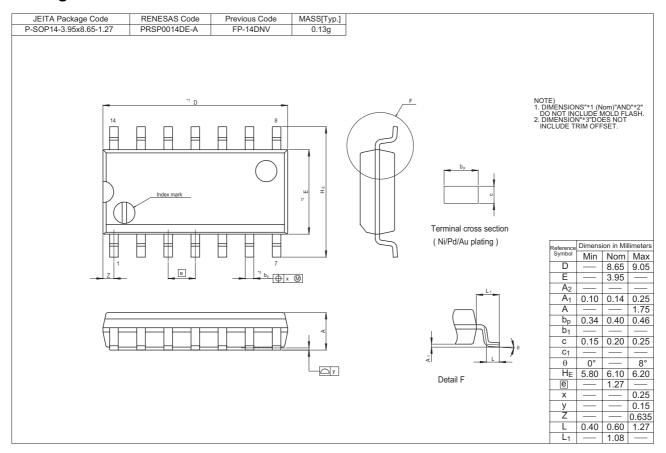
Item	Symbol	V _{CC} (V)		Ta = 25°C		Unit	Test Conditions
item	Syllibol	VCC (V)	Min	Тур	Max	Offic	
Quiet output, maximum dynamic V _{OL}	V _{OL (P)}	3.3	_	0.3	0.8	V	
Quiet output, minimum dynamic V _{OL}	V _{OL (V)}	3.3	_	-0.1	-0.8	V	
High-level dynamic input voltage	V _{IH (D)}	3.3	2.31	_	_	V	
Low-level dynamic input voltage	V _{IL (D)}	3.3	_	_	0.99	V	

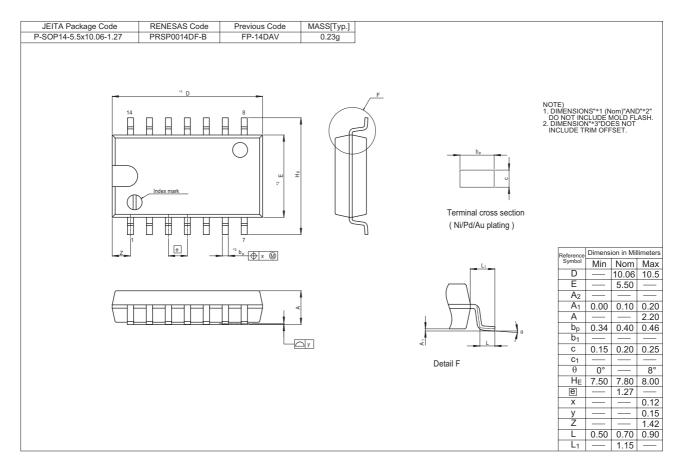
Test Circuit

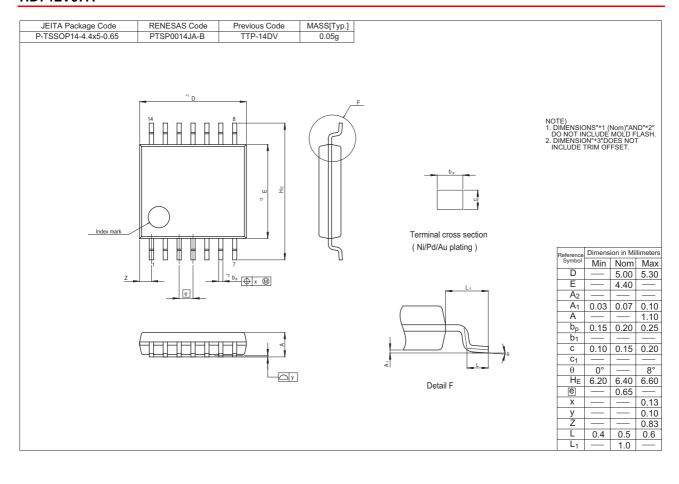




Package Dimensions







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